

MBR20V200CTH/FCTH

Trench MOS Barrier Schottky Rectifier - 20Amp 200Volt

Features

- -Plastic package has Underwriters Laboratory Flammability Classifications 94V-0
- -High Junction Temperature Capability
- -Low forward voltage, high current capability
- -High surge capacity
- -Low power loss, high efficiency
- -Halogen-Free

Application

-AC/DC Switching Adaptor and other Switching Power Supply

☐ Absolute maximum ratings

| Symbol | Ratings | Unit | Conditions | |
|----------------|-------------|------|-----------------------------------|--|
| I F(AV) | 20 | Α | Average Forward Current | |
| VRRM | 200 | V | Repetitive Peak Reverse Voltage | |
| IFSM | 150 | Α | Peak Forward Surge Current | |
| VF | 0.69 | V | Forward Voltage Drop | |
| Tj, Tstg | -65 to +150 | °C | Operating and Storage Temperature | |

Electrical characteristics

| Parameters | Symbol | Ratings | | Conditions | |
|--|----------|----------------|----------------|-------------------------|--|
| | VF | TYP. | MAX. | Per Leg at IF = 10A | |
| Instantaneous Forward Voltage | | 0.85V 0.69V | 0.88V 0.72V | Tc = 25°C Tc = 125°C | |
| | lr | TYP. | MAX. | Per Leg at VR = 200V | |
| Reverse Leakage Current | | 15uA 15mA | 200uA 30mA | Tc = 25°C Tc = 125°C | |
| | Re (j-c) | 2.2 °C/W | | Per Leg | |
| Typical Thermal Resistance, Junction to Case | | | | TO-220AB | |
| | | 4.5 °C/W | | ITO-220AB | |

Note: 1.Mounted on P.C.B with copper pad size 20mm x 30mm, thickness 1.5mm

December 2018 / Rev.7.2

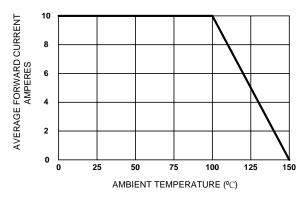
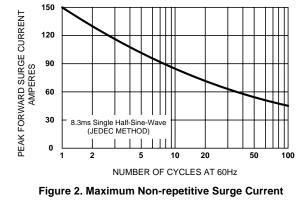


Figure 1. Forward Current Derating Curve



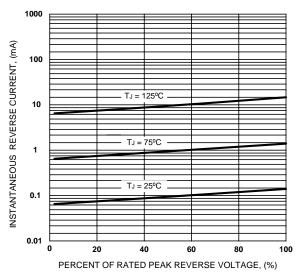


Figure 3. Typical Reverse Characteristics

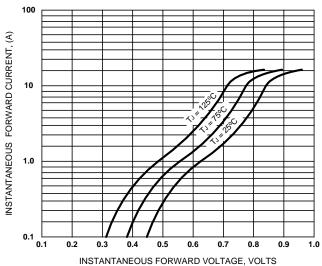


Figure 4. Typical Forward Characteristics

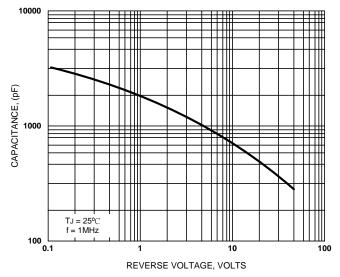
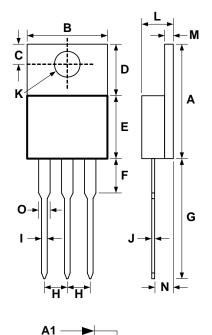


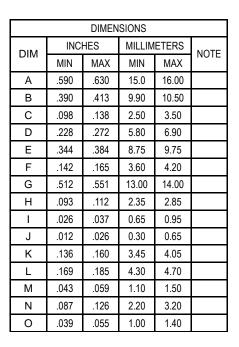
Figure 5. Typical Junction Capacitance

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T0-220AB

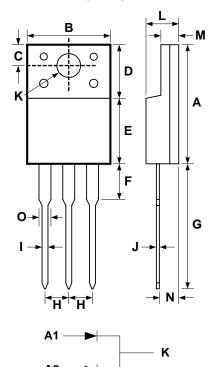


- K



MBR20V200FCTH

ITO-220AB



| DIMENSIONS | | | | | | | | | |
|------------|--------|------|--------|-------|------|--|--|--|--|
| DIM | INCHES | | MILLIM | NOTE | | | | | |
| | MIN | MAX | MIN | MAX | NOTE | | | | |
| Α | .598 | .638 | 15.20 | 16.20 | | | | | |
| В | .386 | .410 | 9.80 | 10.40 | | | | | |
| С | .098 | .138 | 2.50 | 3.50 | | | | | |
| D | .232 | .276 | 5.90 | 7.00 | | | | | |
| Е | .344 | .384 | 8.75 | 9.75 | | | | | |
| F | .118 | .142 | 3.00 | 3.60 | | | | | |
| G | .472 | .532 | 12.00 | 13.50 | | | | | |
| Н | .093 | .112 | 2.35 | 2.85 | | | | | |
| ı | .026 | .037 | 0.65 | 0.95 | | | | | |
| J | .012 | .026 | 0.30 | 0.65 | | | | | |
| K | .124 | .148 | 3.15 | 3.75 | | | | | |
| L | .173 | .189 | 4.40 | 4.80 | | | | | |
| М | .091 | .106 | 2.30 | 2.70 | | | | | |
| N | .094 | .134 | 2.40 | 3.40 | | | | | |
| 0 | .039 | .055 | 1.00 | 1.40 | | | | | |



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